

PUMB2-Q

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 47 k Ω , R2 = 47 k Ω

4 January 2023

Product data sheet

1. General description

PNP/PNP double Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PUMD12-Q NPN/NPN complement: PUMH2-Q

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Low current peripheral driver
- · Control of IC inputs
- · Replaces general-purpose transistors in digital applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor	Per transistor							
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V	
Io	output current			-	-	-100	mA	
R1	bias resistor 1 (input)		[1]	33	47	61	kΩ	
R2/R1	bias resistor ratio		[1]	8.0	1	1.2		

[1] See "Test information" for resistor calculation and test conditions.



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	П6 П5 П4	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2		R2 R1
6	O1	output (collector) TR1	☐1 ☐2 ☐3 TSSOP6 (SOT363)	
			133010 (301303)	GND1 I1 O2
				006aaa212

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PUMB2-Q		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMB2-Q	B%2

[1] % = placeholder for manufacturing site code

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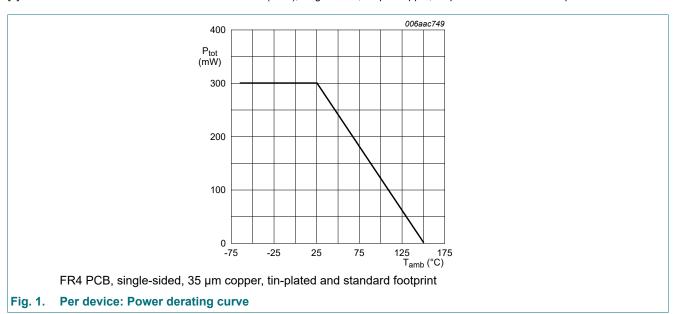
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or					
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V _{CEO}	collector-emitter voltage	open base		-	-50	V
V_{EBO}	emitter-base voltage	open collector		-	-10	V
V _I	input voltage	positive		-	10	V
		negative		-	-40	V
Io	output current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.



50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 47 k Ω , R2 = 47 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

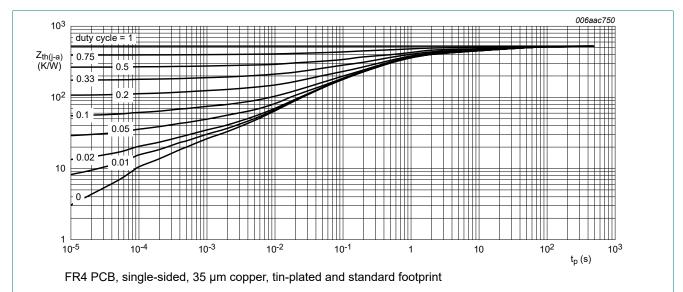


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

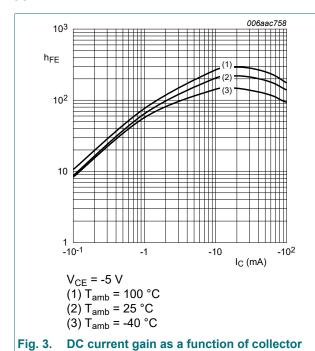
50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 47 k Ω , R2 = 47 k Ω

10. Characteristics

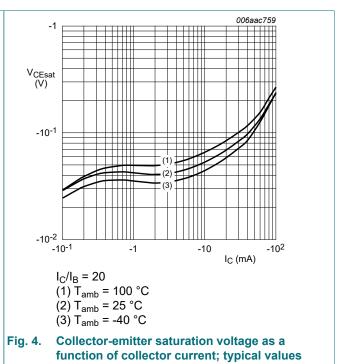
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
V _{(BR)CBO}	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A; T _{amb} = 25 °C		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I _C = -2 mA; I _B = 0 A; T _{amb} = 25 °C	; = -2 mA; I _B = 0 A; T _{amb} = 25 °C		-	-	V
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	' _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C		-	-100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	-100	nA
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-90	μΑ
h _{FE}	DC current gain	V_{CE} = -5 V; I_{C} = -5 mA; T_{amb} = 25 °C		80	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	-150	mV
$V_{I(off)}$	off-state input voltage	V_{CE} = -5 V; I_{C} = -100 μ A; T_{amb} = 25 °C		-	-1.2	-0.8	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I_{C} = -2 mA; T_{amb} = 25 °C		-3	-1.6	-	V
R1	bias resistor 1 (input)		[1]	33	47	61	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	180	-	MHz

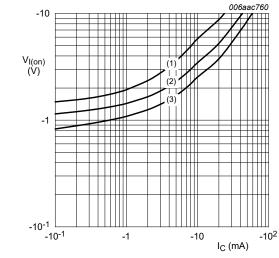
- [1] See "Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor



current; typical values

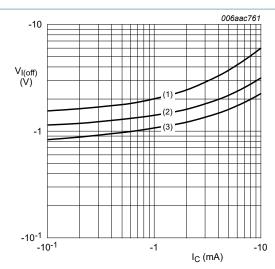


50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 47 k Ω , R2 = 47 k Ω



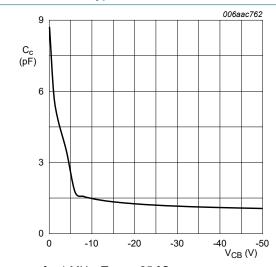
V_{CE} = -0.3 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C





V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Off-state input voltage as a function of collector current; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$

Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values

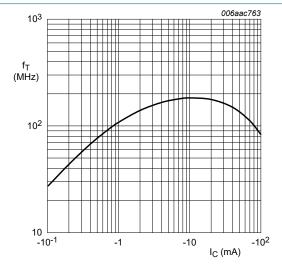


Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 47 k Ω , R2 = 47 k Ω

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

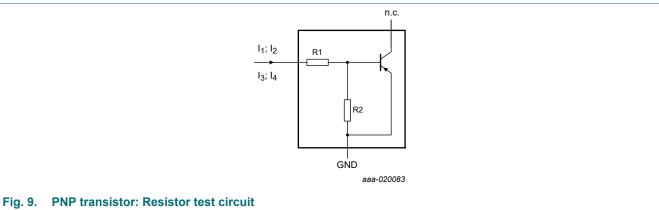
Resistor calculation

Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$



PNP transistor: Resistor test circuit

Resistor test conditions

Table 8. Resistor test conditions

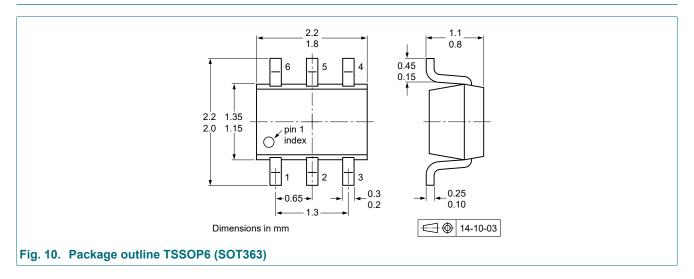
Per transistor

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	l ₂	l ₃	14
PUMB2-Q	47	47	-55 μΑ	-105 μA	55 µA	105 μΑ

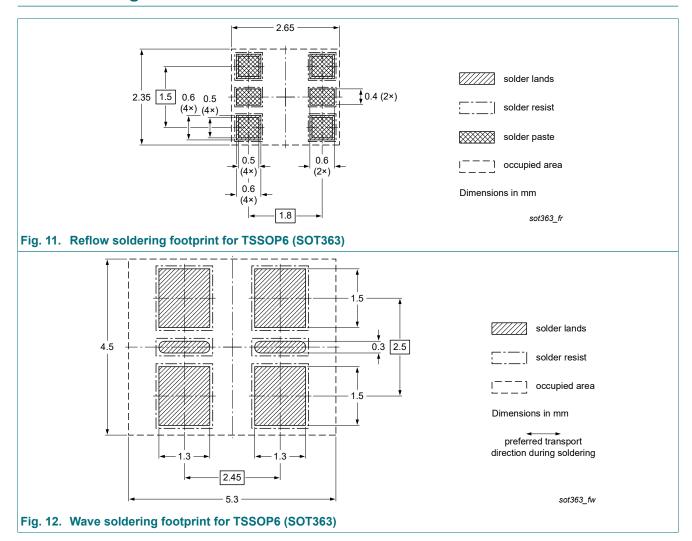
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50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 47 k Ω , R2 = 47 k Ω

12. Package outline



13. Soldering



50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 47 k Ω , R2 = 47 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMB2-Q v.1	20230104	Product data sheet	-	-

50 V, 100 mA PNP/PNP resistor-equipped double transistor; R1 = 47 k Ω , R2 = 47 k Ω

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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